

Supporting information

Solvent-free Crystallization of Zeolitic Imidazolate Framework Membrane via Layer-by-Layer Deposition

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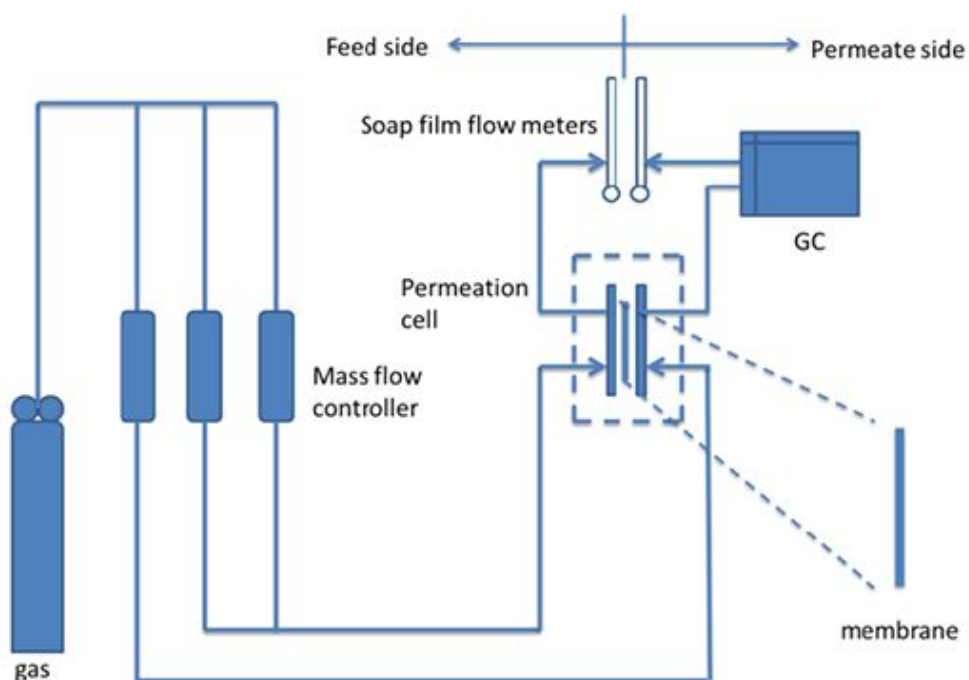


Figure S1. Schematic diagram of gas separation test device.

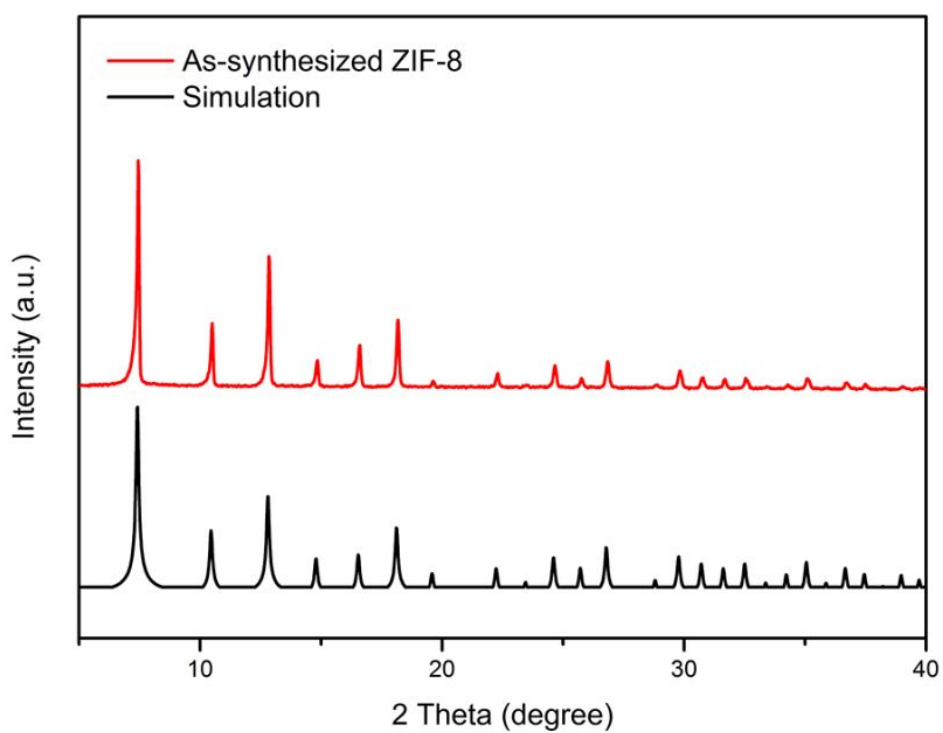


Figure S2. PXRD patterns of the simulated ZIF-8 material (black) and the as-synthesized ZIF-8 powder (red).

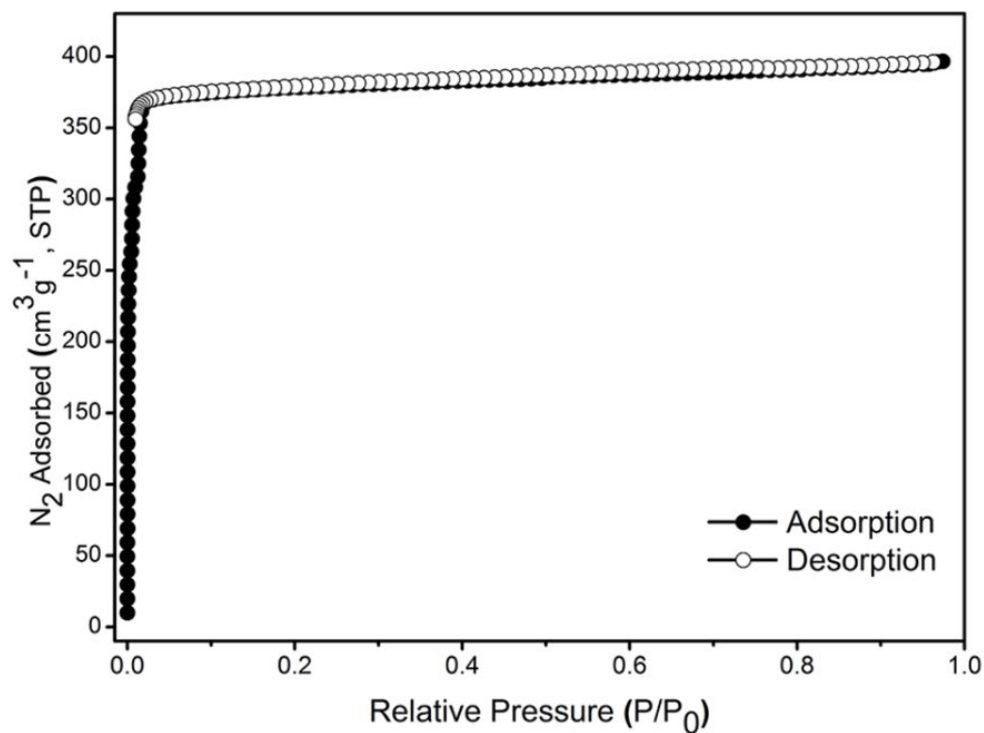


Figure S3. Nitrogen adsorption–desorption isotherm of the formed ZIF-8 sample at 77 K.

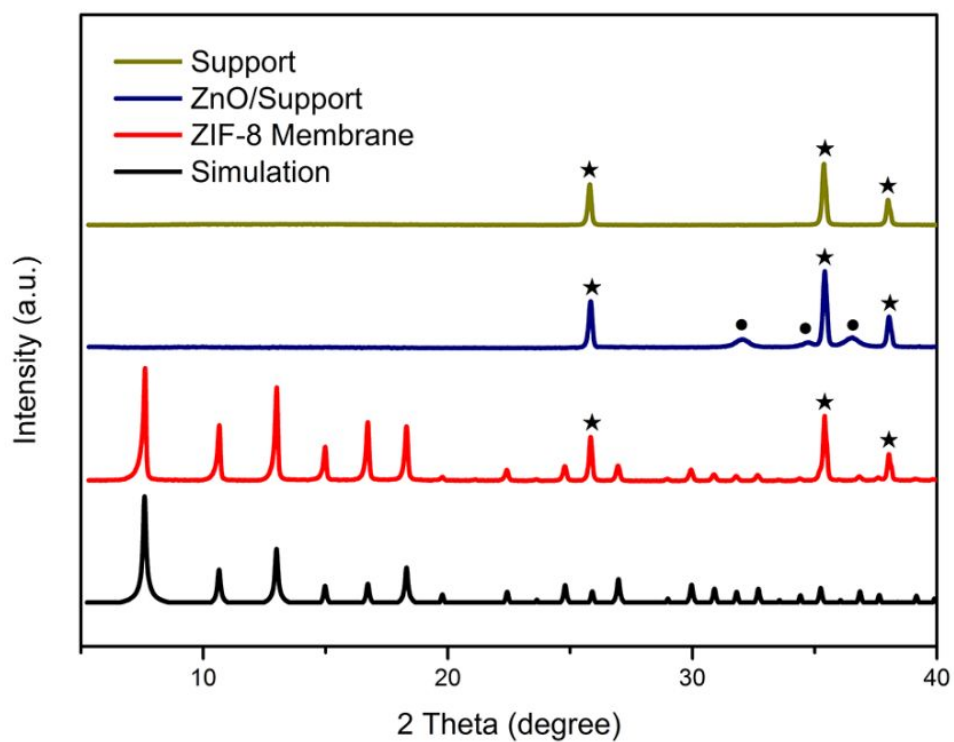


Figure S4. PXRD patterns of the bare Al₂O₃ support (dark yellow), the ZnO-coated Al₂O₃

support (blue), the as-synthesized ZIF-8 membrane (red), the simulated ZIF-8 material (black). (★Al₂O₃ ●ZnO)

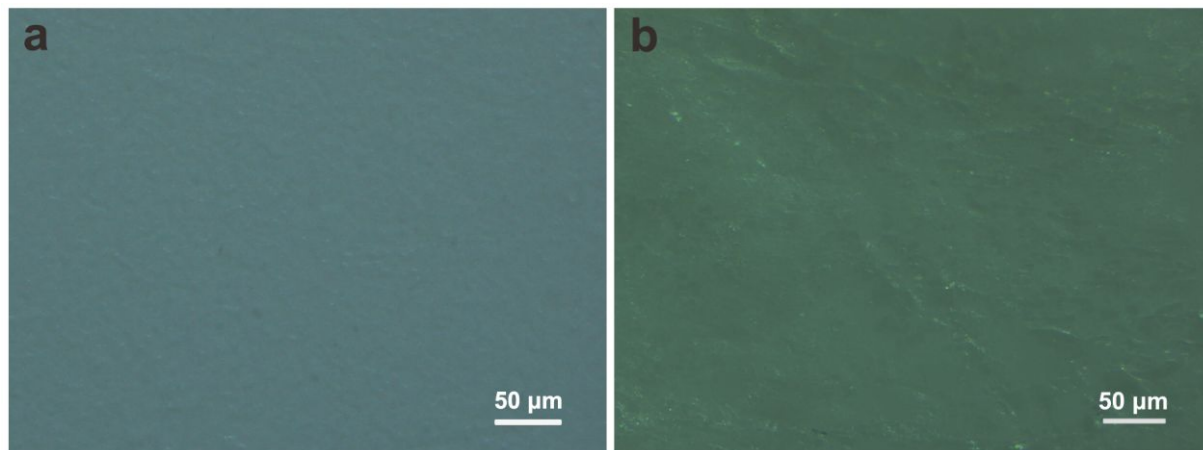


Figure S5. Leica Optic micrographs for the ZnO-coated layer (a) and Hmim layer (b) on the Al₂O₃ support.

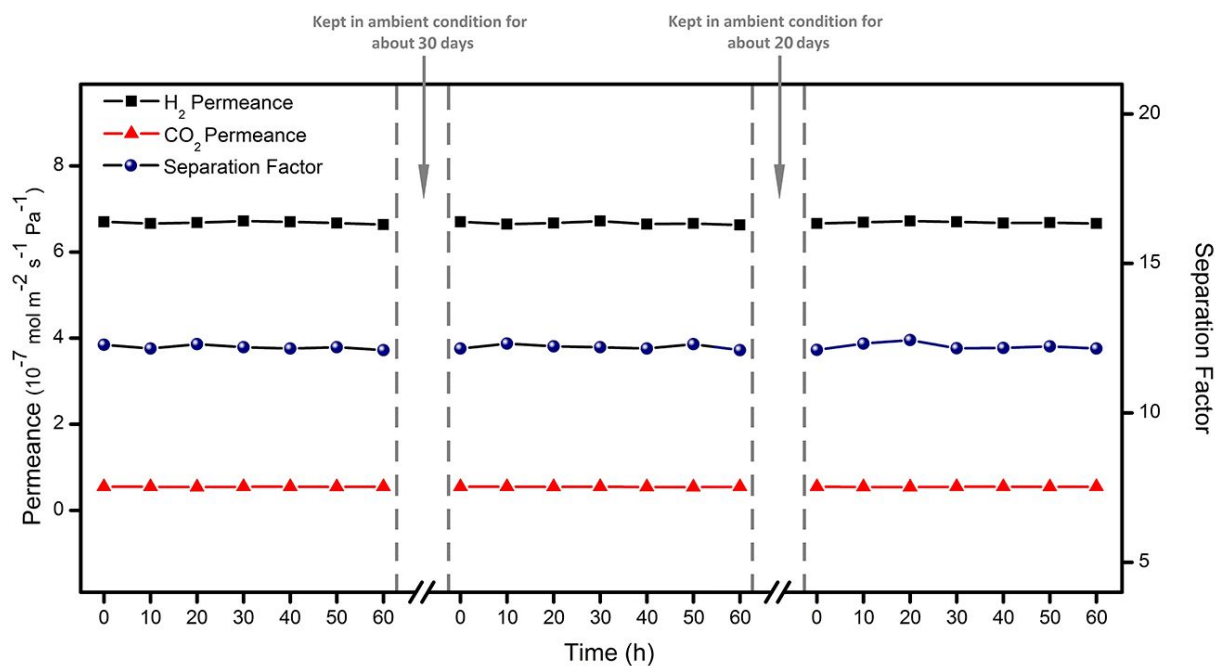


Figure S6. Long-term stability and recyclability measurement of the ZIF-8 membrane prepared by solvent-free method. Equimolar H₂/CO₂ mixture was used as feed gas. Experiment was conducted at 25°C under 1 bar.

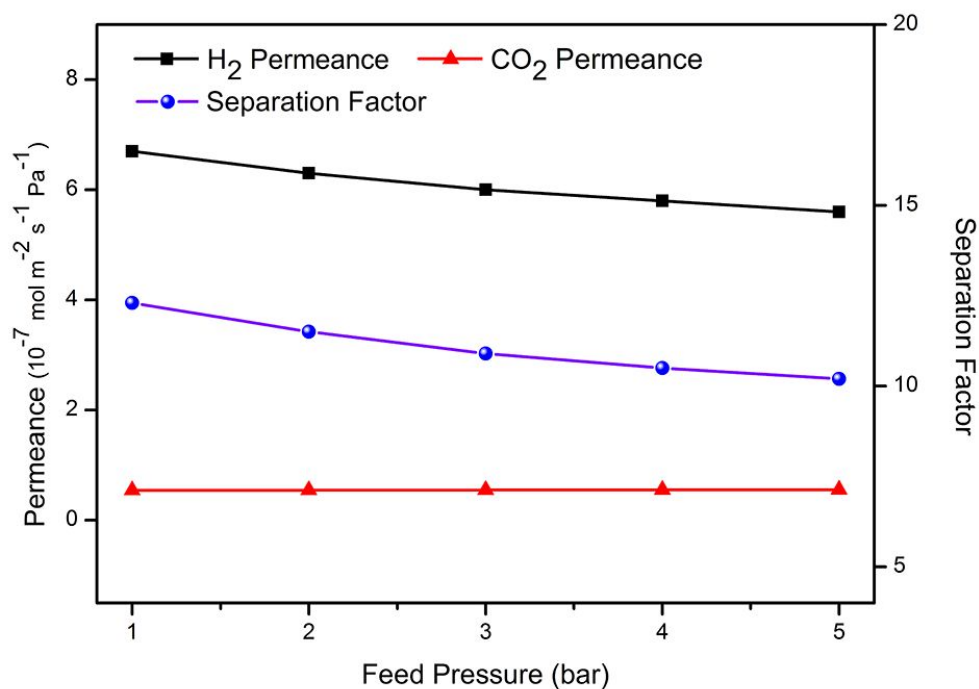


Figure S7. Separation performance of as-prepared ZIF-8 membrane as a function of feed pressure at room temperature.

Table S1. Mixture gas permeances ($10^{-7} \text{ mol m}^{-2} \text{ s}^{-1} \text{ Pa}^{-1}$) and separation factors (H_2 versus other gases) of the ZIF-8 membranes at 25°C and 1 bar.

Gas(i/j)	Permeance(i)	Permeance(j)	Knudsen content	Separation factor
H ₂ /CO ₂	6.70	0.55	4.69	12.28
H ₂ /N ₂	7.10	0.95	3.74	7.48
H ₂ /CH ₄	7.20	0.83	2.83	8.70

Table S2. Mix gas permeances and separation factors of three ZIF-8 membranes were tested at 25°C and 1 bar.

Sample	Permeance (H ₂) ($10^{-7} \text{ mol} \cdot \text{m}^{-2} \cdot \text{s}^{-1} \cdot \text{Pa}^{-1}$)	Separation factor (H ₂ /CO ₂)
M1	6.70	12.28
M2	6.67	12.24
M3	6.75	12.31

Table S3. Comparison of gas permeation properties (H_2 permeance and H_2/CO_2 selectivity) of ZIF-8 membranes reported previously.

Support	Synthesis Method	Thickness (μm)	Permeance (H_2) ($10^{-7}\text{mol}\cdot\text{m}^{-2}\cdot\text{s}^{-1}\cdot\text{Pa}^{-1}$)	Selectivity (H_2/CO_2)	Refs
Titania	Microwave-Assisted Solvothermal Synthesis	30 μm	0.6	4.54 ^a	19
$\alpha\text{-Al}_2\text{O}_3$	Liquid phase epitaxy	1.5 μm	0.19	4.63 ^a	20
Al_2O_3 Hollow fiber	Repeated growth	6 μm	1.7	7.1	40
$\gamma\text{-Al}_2\text{O}_3$	LDH buffer layer modification and solvothermal growth	20 μm	1.4	4.2	46
$\alpha\text{-Al}_2\text{O}_3$	Activation of ZnO Nanorods and solvothermal growth	6 μm	1.6	4.6	47
PAN HF	Surface chemical modification and solvothermal growth	1 μm	3.05	6.85	48
$\gamma\text{-Al}_2\text{O}_3$	Growth of LDH membrane and then solvothermal treatment	2 μm	0.35	4.2	49
PVDF	Chemical modification of support and solvothermal growth	30 μm	19.03	12.42	50
$\alpha\text{-Al}_2\text{O}_3$ tube	Activation of ZnO layer and then solvothermal growth	8 μm	2.75	3.39	51
AAO	Electrophoretic nuclei assembly	0.5 μm	83	7.3 ^a	52
PVDF Hollow fiber	Hydrothermal sol-gel coating of TiO_2 layer on modified support and then solvothermal growth	1 μm	201	7.04 ^a	53

BBPO	Simultaneous Surface chemistry and pore structure modification	0.2 μm	20.5	12.8 ^a	54
$\alpha\text{-Al}_2\text{O}_3$ tube	APTES monolayer modification and cycling precursors	2 μm	4.3	3.54 ^a	55
$\alpha\text{-Al}_2\text{O}_3$	Surface chemical modification	12 μm	1.7	3.3 ^a	56
$\alpha\text{-Al}_2\text{O}_3$	Solvent-free crystallization	7 μm	6.7	12.28	This work

^aIdeal separation factor